## **APPLICATION DATA SHEET**

Electronic Version v14

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Title of Invention

[SPLIT GATE FLASH MEMORY CELL AND MANUFACTURING METHOD THEREOF]

Application Type: regular, utility
Attorney Docket Number: 11080-US-PA

Correspondence address:

Customer Number: 31561

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as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.